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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appl. No. : 10/727,595  
Applicant : Gerhard Enders  
Filed : December 5, 2003  
TC/A.U. : 2811  
Examiner : OWENS, Douglas W.  
Confirmation No. : 7500  
Docket No. : 0928.0006C  
Customer No. : 27896  
Title : Integrated Semiconductor Memory with a Selection  
Transistor Formed at a Ridge (as amended)

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

**TRANSMITTAL LETTER**

Enclosed are the following documents in response to the Notice of Non-Compliant Amendment mailed March 21, 2005 for the above-identified application:

- ☒ Response (2 Pages)
- ☒ Copy of Amendment dated February 25, 2005,  
as originally filed (19 pages).
- ☐ Petition for Extension of Time
- ☐ Request for Approval of Drawing Changes
- ☐ Notice of Appeal
- ☐ Associate Power
- ☐ Revocation and New Power
- ☐ Change of Address
- ☐ Return receipt postcard
- ☐ Check No. \_\_\_\_\_ in the amount of \$ \_\_\_\_\_ for the total fee as calculated below
- ☐ Other:



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**AMENDMENT**

Sir:

In response to the Office Action mailed December 1, 2004, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims, which begins on page 13 of this paper.

**Amendments to the Abstract** begin on page 17 of this paper.

**Remarks** begin on page 18 of this paper.